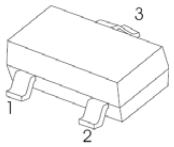
JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD

SOT-23 Plastic-Encapsulate MOSFETS

CJ502K P-CHANNEL MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$MAX	I_D
-50 V	8Ω@-10V	-180mA
	10Ω@-5V	

SOT-23



1. GATE
2. SOURCE
3. DRAIN

DESCRIPTION

These miniature surface mount MOSFETs reduce power loss conserve energy, making this device ideal for use in small power management circuitry.

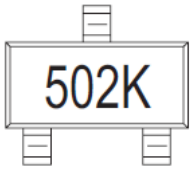
FEATURE

- Energy efficient
- Miniature surface mount package saves board space
- With protection diode between gate and source
- Very fast switching

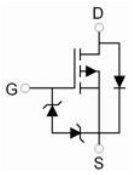
APPLICATION

- DC−DC converters, power management in portable battery−powered products such as computers, printers, cellular and cordless telephones.
- Relay driver
- High-speed line driver
- High-side load switch
- Switching circuits

MARKING



Equivalent Circuit



MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-50	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current (note 1)	I_D	-0.18	A
Pulsed Drain Current @t_p <10 μs	I_{DM}	-0.7	A
Power Dissipation (note 2)	P_D	350	mW
Power Dissipation(note 1)		420	mW
Thermal Resistance from Junction to Ambient (note 2)	$R_{\theta JA}$	357	℃/W
Thermal Resistance from Junction to Ambient (note 1)		298	℃/W
Junction Temperature	T_J	150	℃
Storage Temperature	T_{STG}	-55~+150	℃
Maximum Lead Temperature for Soldering Purposes , Duration for 5 Seconds	T_L	260	℃

1. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm^2
2. Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

MOSFET ELECTRICAL CHARACTERISTICS

T_a=25℃ unless otherwise specified

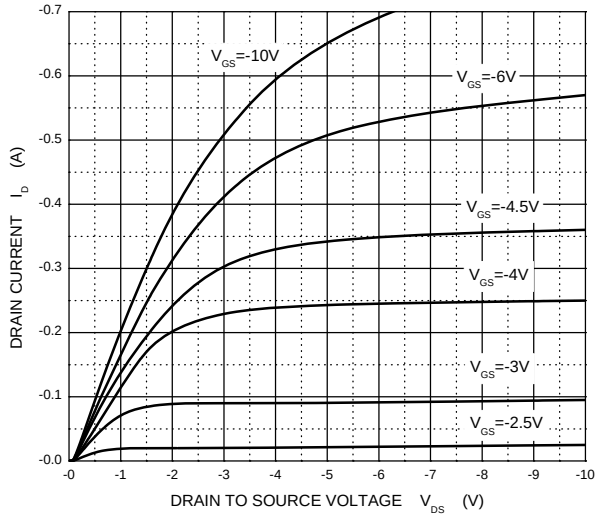
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =-250μA	-50			V
Zero gate voltage drain current	I_{DSS}	V_{DS} =-50V,V_{GS} = 0V			-15	μA
		V_{DS} =-25V,V_{GS} = 0V			-0.1	μA
Gate-body leakage current	I_{GSS}	V_{GS} =±20V, V_{DS} = 0V			±10	μA
Gate threshold voltage (note 1)	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =-250μA	-0.9		-2	V
Drain-source on-resistance (note1)	$R_{DS(on)}$	V_{GS} =-5V, I_D =-0.1A		5.5	10	Ω
		V_{GS} =-10V, I_D =-0.1A		4.1	8	Ω
Forward transconductance (note 1)	g_{FS}	V_{DS}=-25V; I_D=-100mA	50			mS
DYNAMIC CHARACTERISTICS (note 2)						
Input capacitance	C_{iss}	V_{DS} =-5V,V_{GS} =0V,f =1MHz		30		pF
Output capacitance	C_{oss}			10		pF
Reverse transfer capacitance	C_{rss}			5		pF
SWITCHING CHARACTERISTICS (note 2)						
Turn-on delay time	$t_{d(on)}$	V_{DD}=-15V, R_L=50Ω, I_D =-2.5A		2.5		ns
Turn-on rise time	t_r			1		ns
Turn-off delay time	$t_{d(off)}$			16		ns
Turn-off fall time	t_f			8		ns
SOURCE−DRAIN DIODE CHARACTERISTICS						
Continuous current	I_S				-0.18	A
Pulsed current	I_{SM}				-0.7	A
Diode forward voltage (note 1)	V_{DS}	I_S=-0.13A, V_{GS} = 0V			-2.2	V

Notes :

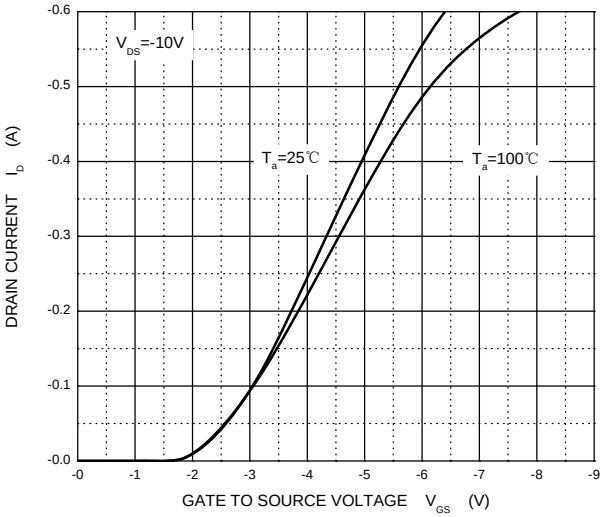
1. Pulse Test : Pulse Width≤300μs, Duty Cycle≤2%.
2. Guaranteed by design, not subject to producting.

Typical Characteristics

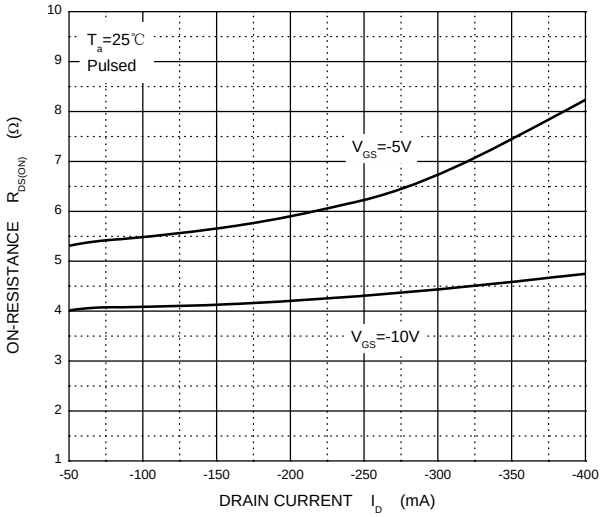
Output Characteristics



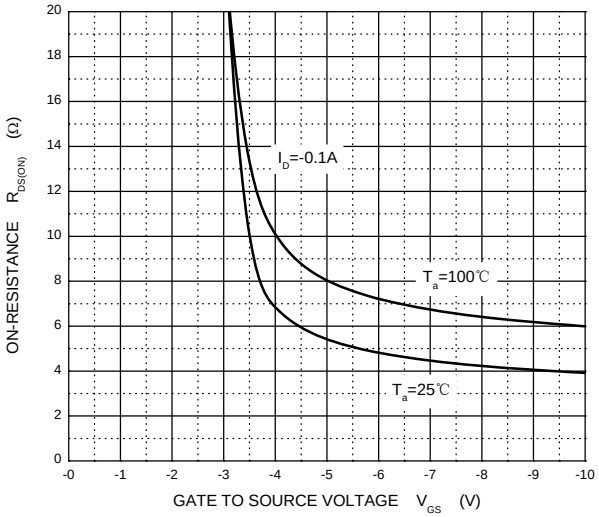
Transfer Characteristics



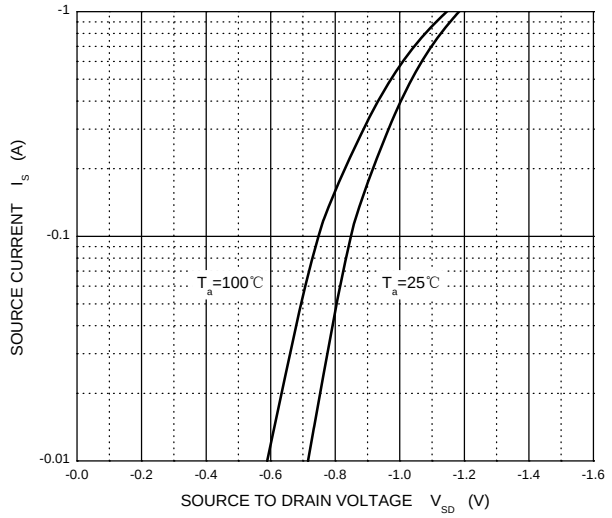
$R_{DS(ON)}$ —— I_D



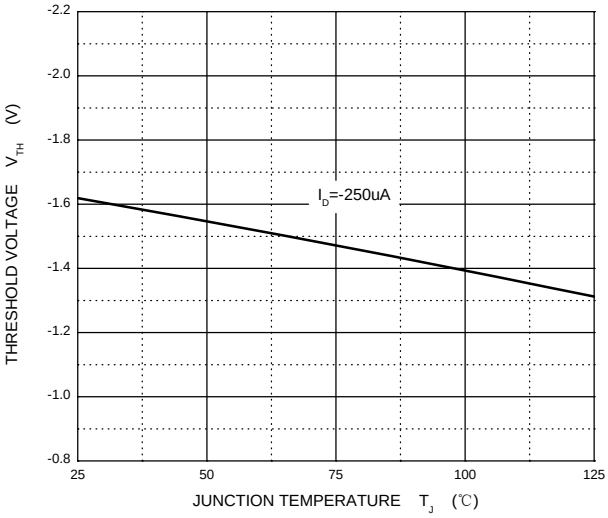
$R_{DS(ON)}$ —— V_{GS}



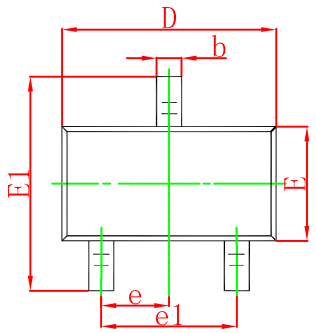
I_S —— V_{SD}

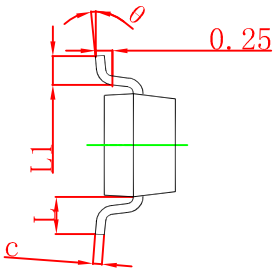


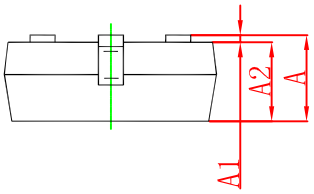
Threshold Voltage



SOT-23 Package Outline Dimensions

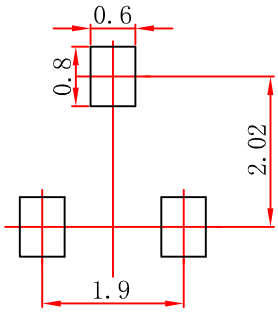






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout

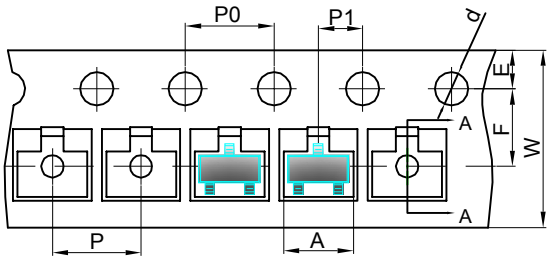


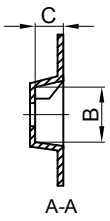
Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

NOTICE
JSCJ reserves the right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOT-23 Tape and reel

SOT-23 Embossed Carrier Tape



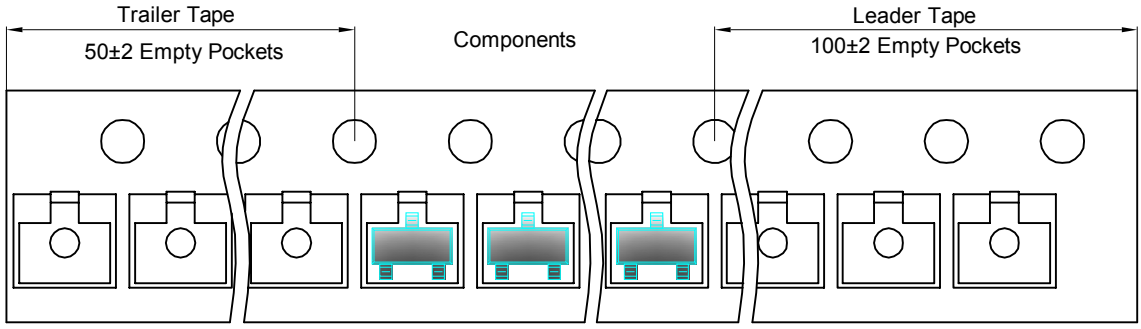


Packaging Description:

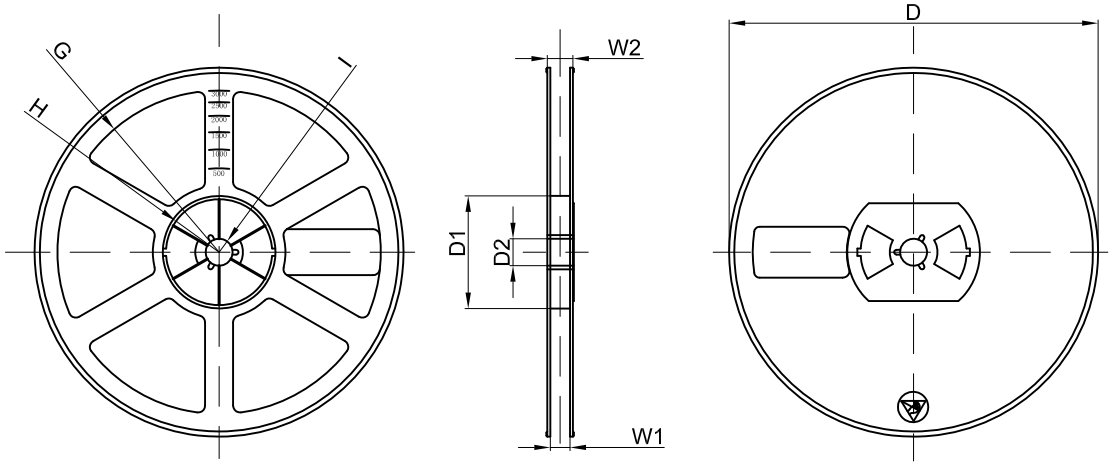
SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	

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